

# UNISONIC TECHNOLOGIES CO., LTD

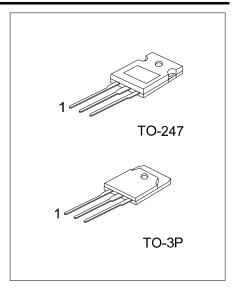
20N60 Power MOSFET

# 20A, 600V N-CHANNEL POWER MOSFET

#### **DESCRIPTION**

The UTC 20N60 is an N-channel enhancement mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology is specialized in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

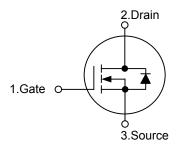
The UTC 20N60 is universally applied in motor control, UPS, DC choppers and switch-mode and resonant-mode power supplies.



#### **FEATURES**

- \*  $R_{DS(ON)} = 0.45\Omega @V_{GS} = 10V$
- \* High switching speed

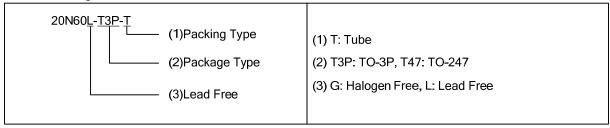
#### **SYMBOL**



#### ORDERING INFORMATION

Ordering Number		Doolsons	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
20N60L-T3P-T	20N60G-T3P-T	TO-3P	G	D	S	Tube	
20N60L-T47-T	20N60G-T47-T	TO-247	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



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# ■ ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT		
Drain-Source Voltage		$V_{ extsf{DSS}}$	600	V		
Gate-Source Voltage		$V_{GSS}$	±20	٧		
Drain Current	Continuous		$I_{D}$	20	Α	
	Pulsed		I <sub>DM</sub>	80	Α	
Avalanche Energy	Single Pul	sed(Note 2)	E <sub>AS</sub>	1200	mJ	
Dower Dissinction		TO-3P	0	300	W	
Power Dissipation		TO-247	$P_{D}$	370	VV	
Junction Temperature		T <sub>J</sub>	+150	°C		
Storage Temperature		$T_{STG}$	-55~+150	°C		

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

# ■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
lumation to Occa-	TO-3P	0	0.42	00/11/	
Junction to Case	TO-247	AlC	0.34	°C/W	

### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V				V	
Drain-Source Leakage Current	$I_{DSS}$	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V			10	μΑ	
Gate- Source Leakage Current Forward		$V_{GS}$ =+20V, $V_{DS}$ =0V			+100	nA	
Reverse	$I_{GSS}$	V <sub>GS</sub> =-20V, V <sub>DS</sub> =0V			-100	nA	
ON CHARACTERISTICS							
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$			4.0	V	
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A, Pulse test, t≤300µs, duty cycle d≤2%		0.32	0.45	Ω	
DYNAMIC PARAMETERS				ı			
Input Capacitance	C <sub>ISS</sub>			4500		рF	
Output Capacitance	Coss	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		420		pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>			140		pF	
SWITCHING PARAMETERS							
Total Gate Charge	$Q_G$	V <sub>GS</sub> =10V, V <sub>DS</sub> =300V, I <sub>D</sub> =10A (Note 1, 2)		150	170	nC	
Gate to Source Charge	$Q_{GS}$			29	40	nC	
Gate to Drain Charge	$Q_GD$			60	85	nC	
Turn-ON Delay Time	$t_{D(ON)}$	$V_{GS}$ =10V, $V_{DS}$ =300V, $I_{D}$ =10A, $R_{G}$ =2 $\Omega$ , (Note 1, 2)		20	40	ns	
Rise Time	$t_R$			43	60	ns	
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			70	90	ns	
Fall-Time	$t_{F}$			40	60	ns	
SOURCE- DRAIN DIODE RATINGS AND	CHARACT	ERISTICS					
Maximum Body-Diode Continuous		V <sub>GS</sub> =0V			20	Α	
Current	I <sub>S</sub>				20	А	
Maximum Body-Diode Pulsed Current	I <sub>SM</sub>	Repetitive			80	Α	
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	I <sub>F</sub> =I <sub>S</sub> , V <sub>GS</sub> =0V, Pulse test, t≤300µs, duty cycle d≤2%			1.5	٧	
Body Diode Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =I <sub>S</sub> ,V <sub>R</sub> =100V,-di/dt=100A/μs(Note 1)		600		ns	

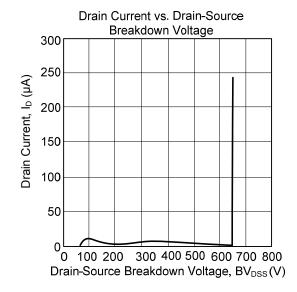
Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle≤2%

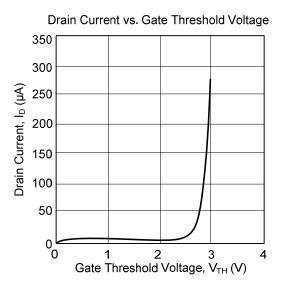
<sup>2.</sup>  $V_{DD}$ =50V, Starting  $T_J$ =25°C, Peak  $I_{AS}$ =20A, L=6mH

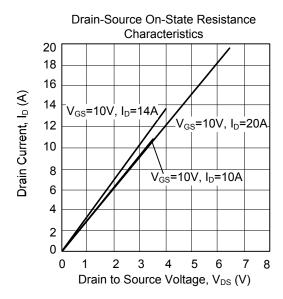
<sup>2.</sup> Essentially independent of operating temperature

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#### TYPICAL CHARACTERISTICS







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